# VS-FCSP05H40TR

**Vishay Semiconductors** 

## FlipKY<sup>®</sup>, Chip Scale Package Schottky Barrier Rectifier, 0.5 A



**FlipKY<sup>®</sup>** 

0.5 A

40 V

0.42 V

10 µA

2 mA

150 °C

5 mJ

### **FEATURES**

- Ultra low V<sub>F</sub> to footprint area
- Very low profile (< 0.6 mm)</li>
- · Low thermal resistance
- · Supplied tested and on tape and reel
- Compliant to RoHS Directive 2002/95/EC

### APPLICATIONS

- · Reverse polarity protection
- · Current steering
- Freewheeling
- Flyback
- Oring

### DESCRIPTION

Vishay's FlipKY® product family utilizes wafer level chip scale packaging to deliver Schottky diodes with the lowest V<sub>F</sub> to PCB footprint area in industry. The three pad 0.9 mm x 1.2 mm devices can deliver up to 0.5 A and occupy only 1.08 mm<sup>2</sup> of board space. The anode and cathode connections are made through solder bump pads on one side of the silicon enabling designers to strategically place the diodes on the PCB. This design not only minimizes board space but also reduces thermal resistance and inductance, which can improve overall circuit efficiency.

Typical applications include hand-held, portable equipment such as cell phones, MP3 players, bluetooth, GPS, PDAs, and portable hard disk drives where space savings and performance are crucial.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	MAX.	UNITS		
V <sub>RRM</sub>		40	V		
I <sub>F(AV)</sub>	Rectangular waveform	0.5	А		
I <sub>FSM</sub>		190	A		
V <sub>F</sub>	0.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.42	V		
TJ		- 55 to 150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-FCSP05H40TR	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	40	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	v		

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COMPLIANT





**PRODUCT SUMMARY** 

I<sub>F(AV)</sub>

 $V_R$ 

V<sub>F</sub> at I<sub>F</sub>

I<sub>RM</sub> max. at 25 °C

I<sub>RM</sub> max. at 125 °C

T<sub>J</sub> max.

 $\mathsf{E}_{\mathsf{AS}}$ 

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_{PCB}$ = 114 °C, rectangular waveform		0.5	
Maximum peak one cycle non-repetitive surge current at 25 °C	<b>I</b> =0.1	I <sub>FSM</sub> 5 μs sine or 3 μs rect. pulse Following any rated 10 ms sine or 6 ms rect. pulse rated V <sub>RRM</sub> applied		190	А
	IFSM		10		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2.0 A, L = 5.0 mH		5	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.5	А

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
		0.5 A	T.I = 25 °C	0.48	0.52	v
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	1 A		0.54 0.58	0.58	
	VFM (")	0.5 A	T 105 %C	0.38	0.42	v
		1 A	T <sub>J</sub> = 125 °C	0.46	0.50	1
			V <sub>R</sub> = Rated V <sub>R</sub>	1	10	μA
		T <sub>J</sub> = 25 °C	V <sub>R</sub> = 20 V	0.2	0.5	
			V <sub>R</sub> = 10 V	0.08	0.25	
Maximum reverse	. (1)		V <sub>R</sub> = 5 V	0.05	0.15	
leakage current See fig. 2	I <sub>RM</sub> <sup>(1)</sup>		V <sub>R</sub> = Rated V <sub>R</sub>	0.5	2	
		T 105 %O	V <sub>R</sub> = 20 V	0.2	1	
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = 10 V	0.15	0.8	mA
			V <sub>R</sub> = 5 V	0.125	0.5	
Maximum junction capacitance	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	90	pF
Maximum voltage rate of charge	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

#### Note

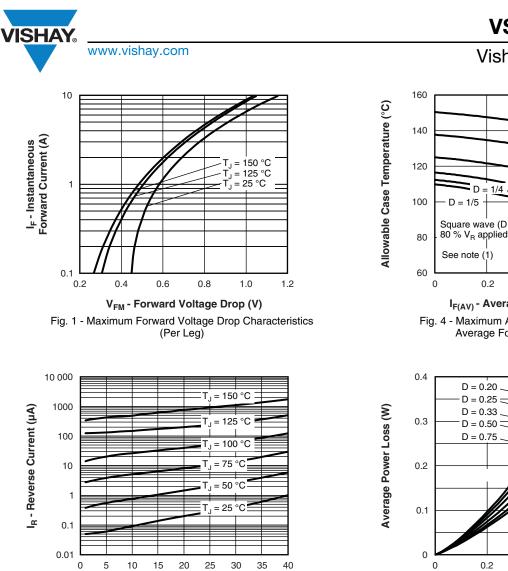
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

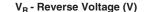
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 55 to 150	°C	
Typical thermal resistance, junction to PCB	R <sub>thJL</sub> <sup>(2)</sup>	DC operation	35	°C/W	
Maximum thermal resistance, junction to ambient R <sub>thJA</sub>			150	0/11	

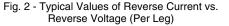
#### Notes

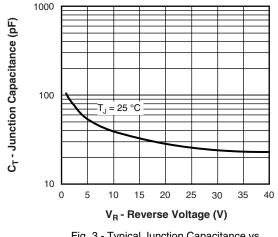
(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

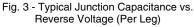
<sup>(2)</sup> Mounted on minimum footprint PCB





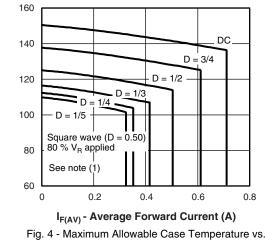








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Average Forward Current (Per Leg)

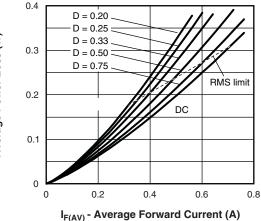
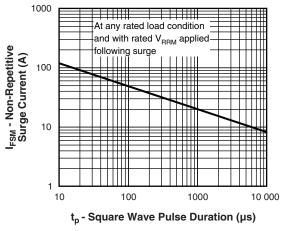
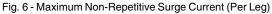


Fig. 5 - Forward Power Loss Characteristics (Per Leg)





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at 80 % V<sub>R</sub> applied

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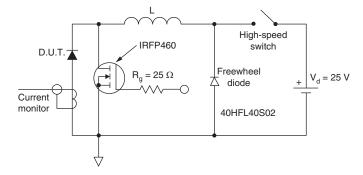


Fig. 7 - Unclamped Inductive Test Circuit

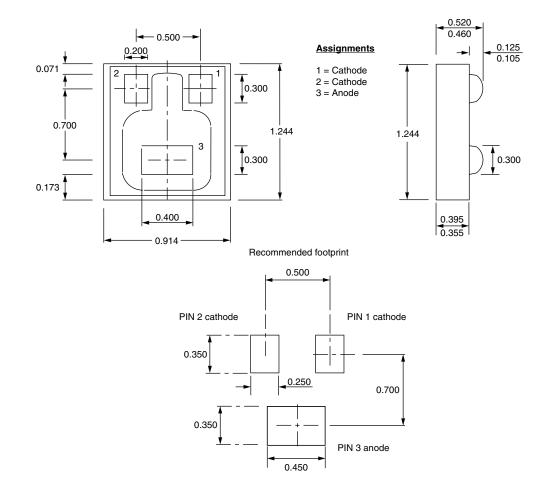
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Packaging information	www.vishay.com/doc?95062		
SPICE model	www.vishay.com/doc?95318		

Vishay High Power Products



FlipKY<sup>®</sup> 0.5 A/0.75 A

### **DIMENSIONS** in millimeters



#### Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Controlling dimension: millimeter



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